

## СПИСЪК

НА ЗАБЕЛЯЗАНИТЕ НЕЗАВИСИМИ ЦИТИРАНИЯ  
на доц. д-р Ирина Бинева за участие в конкурса  
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**Група от показатели Д (включва показател 11):**

**Показател 11 – Цитирания в научни издания, монографии, колективни томове и патенти, реферирани и индексирани в световноизвестни бази данни с научна информация (Web of Science и Scopus) За участие в конкурса 171 (Необходими - 200 т.; Събрани –342т.)**

**D. Nesheva, C. Raptis, A. Perakis, I. Bineva, Z. Aneva, Z. Levi, S. Alexandrova, H. Hofmeister, “Raman scattering and photoluminescence from Si nanoparticles in annealed SiO<sub>x</sub> thin films”, *J. Appl. Phys.*, **92** (2002) 4678-83.**

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